MOSFET – Power, Single, **N-Channel 40 V, 17.9 mΩ, 22 A**

Features

- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



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V _{(BR)DSS}	R _{DS(on)}	I _D
40 V	17.9 m Ω @ 10 V	22 A

DO

MAXIMUM RATINGS (T_{.1} = 25°C unless otherwise noted) Value Unit Parameter Symbol v 40 V_{DSS} V Gate-to-Source Voltage V_{GS} ± 20 Continuous Drain Cur-A I_D 23 $T_C = 25^{\circ}C$ rent R_{0JC} (Notes 1 & 3) $T_{\rm C} = 100^{\circ}{\rm C}$ 16 Steadv State Power Dissipation R_{0.IC} P_{D} $T_C = 25^{\circ}C$ 18.3 W (Note 1) 9.1 $T_{C} = 100^{\circ}C$ Continuous Drain T_A = 25°C I_{D} 9.2 А Current R_{0JA} (Notes 1, 2 & 3) T_A = 100°C 65 Steady State Power Dissipation R_{0.IA} w $T_A = 25^{\circ}C$ P_D 2.9 (Notes 1 & 2) T_Δ = 100°C 1.5 **Pulsed Drain Current** T_A = 25°C, t_p = 10 μs 104 A IDM **Operating Junction and Storage Temperature** T_J, T_{stg} -55 to °C 175 Source Current (Body Diode) 15 А I_S Single Pulse Drain-to-Source Avalanche E_{AS} 63 mJ Energy (T_J = 25° C, I_{L(pk)} = 1.7 A) Lead Temperature for Soldering Purposes °C T_{L} 260 (1/8" from case for 10 s)

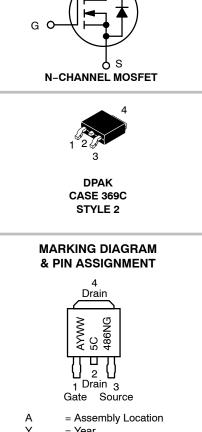
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case (Drain) (Note 1)	$R_{\theta JC}$	8.2	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	51.7	

The entire application environment impacts the thermal resistance values shown, 1. they are not constants and are only valid for the particular conditions noted.

 Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad. 3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



= Year

WW = Work Week 5C486N = Device Code

= Pb-Free Package G

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Drain-to-Source Voltage

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

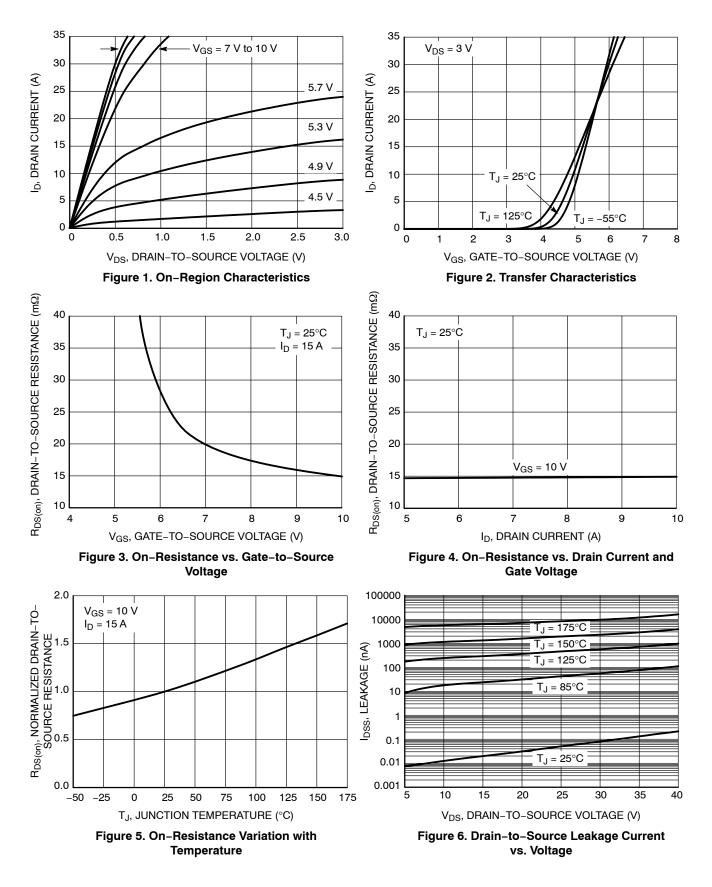
Parameter	Symbol	Test Cond	ition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						-	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				16		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	$V_{GS} = 0 V_{.}$ $T_{J} = 25^{\circ}C$			10	μA
		$V_{DS} = 40 V$	T _J = 125°C			250	1
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{G}$	_S = 20 V			100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D$	= 20 μA	2.0		4.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				6.1		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 10 A			14.9	17.9	mΩ
Forward Transconductance	9 FS	V _{DS} = 3 V, I _D = 10 A			17.5		S
CHARGES, CAPACITANCES AND GATE RE	SISTANCES					-	
Input Capacitance	C _{iss}				380		pF
Output Capacitance	C _{oss}	V_{GS} = 0 V, f = 1.0 MHz, V_{DS} = 25 V			200		-
Reverse Transfer Capacitance	C _{rss}				15		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} = 32 V, I _D = 10 A			14		nC
Threshold Gate Charge	Q _{G(TH)}				2.9		
Gate-to-Source Charge	Q _{GS}				4.3		
Gate-to-Drain Charge	Q _{GD}				2.8		1
Plateau Voltage	V _{GP}				4.6		V
SWITCHING CHARACTERISTICS (Note 5)					•	8	
Turn-On Delay Time	t _{d(on)}				9.0	1	ns
Rise Time	t _r	Voo - 10 V Vo	32 V		14		1
Turn-Off Delay Time	t _{d(off)}	V_{GS} = 10 V, V_{DS} = 32 V, I _D = 10 A, R _G = 2.5 Ω			15		
Fall Time	t _f				3.0		
DRAIN-SOURCE DIODE CHARACTERISTIC	S						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	T _J = 25°C		0.88	1.2	V
		V _{GS} = 0 V, I _S = 10 A	T _J = 125°C		0.77		1
Reverse Recovery Time	t _{BB}	V _{GS} = 0 V, dls/dt = 100 A/μs, I _S = 10 A			27		ns
Charge Time	ta				12		
Discharge Time	tb				15		1
Reverse Recovery Charge	Q _{BB}				10		nC

ORDERING INFORMATION

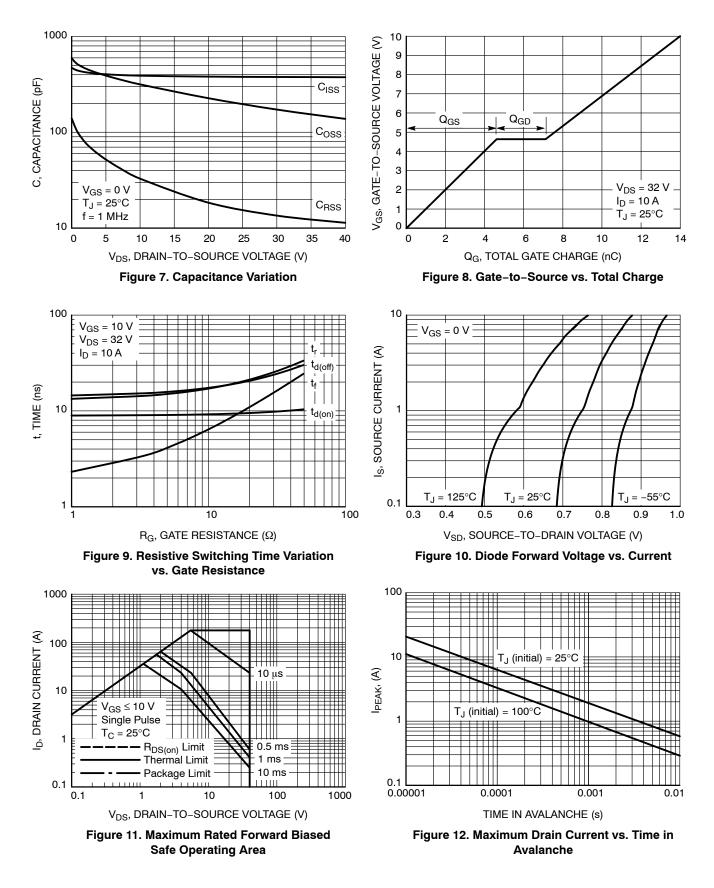
Order Number	Package	Shipping [†]
NVD5C486NT4G	DPAK (Pb–Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

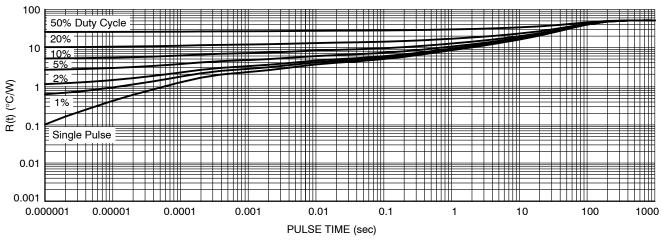


Figure 13. Thermal Characteristics





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